3C91C, 3C92C (TX), 3N243, 3N244, 3N245 (TX), 3N262

Features:

- TO-72 hermetically sealed package
- 1 kVDC electrical isolation
- High current transfer ratio
- TX devices processed to MIL-PRF-19500



Description:

Each device is a high reliability optically coupled isolator that consists of an infrared emitting diode and a NPN silicon phototransistor which are mounted in a hermetically sealed TO-72 package. The **3C91C** and **3C92C** have a 935 nm wavelength, whereas the **3N243**, **3N244**, **3N245** and **3N262** have an 880 nm wavelength. All devices have 0.50" (12.70 mm) leads. Electrical characteristics vary.

TX devices are processed to OPTEK's military screening program patterned after MIL-PRF-19500.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Contact your local representative or OPTEK for more information.

Applications:

- High-voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment





Phototransistor Collector is connected to the Header-Base-Case for ALL versions



General Note

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3C91C, 3C92C (TX), 3N243, 3N244, 3N245 (TX), 3N262



Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Operating Temperature Range	-55° C to +125° C
Storage Temperature Range	-65° C to +150° C
Input to Output Isolation Voltage	± 1 kVDC ⁽¹⁾
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽²⁾

Input Diode

Forward DC Current	40 mA
Reverse Voltage	2.0 V
Power Dissipation	60 mW ⁽³⁾

Output Phototransistor

Continuous Collector Current	30 mA
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5.0 V
Power Dissipation	200 mW ⁽⁴⁾

Notes:

1. Measured with input leads shorted together and output leads shorted together.

2. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

3. Derate linearly 2.0 mW/° C above 25° C.

4. Derate linearly 0.60 mW/° C above 65° C.



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3C91C, 3C92C (TX), 3N243, 3N244, 3N245 (TX), 3N262



Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	ΜΑΧ	UNITS	TEST CONDITIONS
nput Diod	e					
	Forward Voltage			1.2		
	3C91C, 3C92C (TX) 3C91C, 3C92C (TX)	-	-	1.2 1.5		I _F = 2 mA I _F = 50 mA
V_{F}	3N243, 3N244, 3N245 (TX)	0.8	_	1.3	v	$I_F = 30 \text{ mA}$
	3N243, 3N244, 3N245 (TX)	1.0	-	1.5		$I_F = 10 \text{ mA}, T_A = -55^{\circ} \text{ C}$
	3N243, 3N244, 3N245 (TX)	0.7	-	1.2		$I_F = 10 \text{ mA}, T_A = -100^{\circ} \text{ C}$
	3N262	0.8	-	1.5		$I_F = 10 \text{ mA}$
	3N262	1.0	-	1.7		$I_F = 10 \text{ mA}, T_A = -55^{\circ} \text{ C}$
	3N262	0.7	-	1.3		I _F = 10 mA, T _A = -100° C
	Reverse Voltage					
V _R	3C91C, 3C92C (TX)	7	-	-	V	I _R = 0.1 mA
	Reverse Current					
I _R	3C91C, 3C92C (TX)	-	-	1	μA	V _R = 3.0 V
	3N243, 3N244, 3N245 (TX)	-	-	100		V _R = 2.0 V
	3N262	-	-	100		V _R = 2.0 V
C _{IN}	Diode Capacitance				pF	
CIN	3C91C, 3C92C (TX)	-	25	-	Pi	V = 0, f = 1 MHz
Output Pho	ototransistor					
	Collector-Emitter Breakdown Voltage					
V _{(BR)CEO}	3C91C, 3C92C (TX)	50	-	-		I _c = 10.0 mA
V (BR)CEO	3N243, 3N244, 3N245 (TX)	30	-	-	V	I _C = 1.0 mA
	3N262	40	-	-		I _C = 1.0 mA
	Emitter-Collector Breakdown Voltage					
V _{(BR)ECO}	3C91C, 3C92C (TX)	7	-	-	v	$I_c = 10 \ \mu A$
V (BR)ECO	3N243, 3N244, 3N245 (TX)	5	-	-	v	$I_{E} = 100 \ \mu A$
	3N262	7	-	-		I _E = 100 μA
	Collector Dark Current					
I _{CEO}	3C91C, 3C92C (TX)	-	-	10	nA	$V_{CE} = 5 V$
	3C91C, 3C92C (TX)	-	-	50	nA	$V_{CE} = 50 V$
	3N243, 3N244, 3N245 (TX)	-	-	100	nA	$V_{CE} = 10.0 V$
	3N243, 3N244, 3N245 (TX)	-	-	100	μA	$V_{CE} = 10.0 \text{ V}, \text{ T}_{A} = 100^{\circ} \text{ C}$
	3N262	-	-	100	μA	$V_{CE} = 10.0 V$
	3N262	-	-	100	μΑ	V _{CE} = 10.0 V, T _A = 100° C

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3C91C, 3C92C (TX), 3N243, 3N244, 3N245 (TX), 3N262



Electrical Specifications

SYMBOL	PARAMETER	MIN	ТҮР	МАХ	UNITS	TEST CONDITIONS
Coupled						
I _{C(ON)}	On-State Collector Current 3C91C, 3C92C (TX) 3C91C, 3C92C (TX) 3N243 3N243 3N243 3N244 3N244 3N244 3N244 3N244 3N244 3N244 3N244 3N245 (TX) 3N245 (TX) 3N245 (TX) 3N262 3N262 3N262	$\begin{array}{c} 4.0\\ 3.0\\ 1.5\\ 0.3\\ 0.5\\ 0.5\\ 3.0\\ 0.8\\ 1.0\\ 1.0\\ 1.0\\ 1.0\\ 1.5\\ 1.5\\ 1.5\\ 1.5\\ 1.0\\ 1.4\\ 1.0\\ \end{array}$		- 20 - - - - - - - - - - 5 - -	mA	$\begin{split} I_F &= 10 \text{ mA} \text{ , } V_{CE} = 5 \text{ V} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 0.4 \text{ V} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \\ I_F &= 3 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \\ I_F &= 3 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \\ I_F &= 3 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 10.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 10 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 55^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 2.0 \text{ mA} \text{ , } V_{CE} = 5.0 \text{ V} \text{ , } T_A = 100^{\circ} \text{ C} \\ I_F &= 0 \text{ , } T_F = 0 \text{ , } T_F =$
V _{CE} (SAT)	Collector-Emitter Saturation Voltage 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N243, 3N244, 3N245 (TX) 3N243, 3N244, 3N245 (TX) 3N262 3N262 3N262			0.4 0.3 0.3 0.3 0.3 0.3 0.3 0.3	v	$\begin{split} I_F &= 50 \text{ mA}, \ I_C &= 10 \text{ mA} \\ I_F &= 20 \text{ mA}, \ I_C &= 1.50 \text{ mA} \\ I_F &= 20 \text{ mA}, \ I_C &= 3.0 \text{ mA} \\ I_F &= 20 \text{ mA}, \ I_C &= 6.0 \text{ mA} \\ I_F &= 2.0 \text{ mA}, \ I_C &= 0.50 \text{ mA} \\ I_F &= 2.0 \text{ mA}, \ I_C &= 1.0 \text{ mA} \\ I_F &= 2.0 \text{ mA}, \ I_C &= 2.0 \text{ mA} \end{split}$
t _{on}	Turn-on Time 3C91C, 3C92C (TX)	-	-	9	μs	V_{cc} = 5 V, I_c = 2 mA, R_L = 100 Ω
t _{IOFF}	Turn-off Time 3C91C, 3C92C (TX)	-	-	6	μs	V_{cc} = 5 V, I _c = 2 mA, R _L = 100 Ω

Electrical Characteristics (T_A = 25° C unless otherwise noted)

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3C91C, 3C92C (TX), 3N243, 3N244, 3N245 (TX), 3N262



Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
Coupled						
C _{IO}	Input-to-Output Capacitance 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N262		2 - -	2.5 5.0 5.0	pF	$ f = 1 \text{ MHz} \\ V_{IO} = 0 \text{ V, } f = 1.00 \text{ MHz}^{(1)} \\ V_{IO} = 0 \text{ V, } f = 1.00 \text{ MHz}^{(1)} $
I _{IO}	Leakage Input -to-Output 3N243, 3N244, 3N245 (TX) 3N262		-	100 10	nA	$V_{IO} = \pm 1.00 \text{ kVDC}^{(1)}$ $V_{IO} = \pm 1.00 \text{ kVDC}^{(1)}$
R _{io}	Isolation Resistance 3C91C, 3C92C (TX)	10 ⁹	-	-	Ω	V _{IO} = +1 kV
t _r	Output Rise Time 3N243, 3N244, 3N245 (TX) 3N262	-	-	10 20	μs	$\begin{split} V_{CC} &= 10.0 \text{ V}, \text{ I}_{\text{F}} = 10.0 \text{ mA}, \text{ R}_{\text{L}} = 100 \ \Omega^{(2)} \\ V_{CC} &= 10.0 \text{ V}, \text{ I}_{\text{F}} = 5.0 \text{ mA}, \text{ R}_{\text{L}} = 100 \ \Omega^{(2)} \end{split}$
t _f	Output Fall Time 3N243, 3N244, 3N245 (TX) 3N262	-	-	10 10	μs	$\begin{split} V_{CC} &= 10.0 \text{ V}, \text{ I}_{\text{F}} = 10.0 \text{ mA}, \text{ R}_{\text{L}} = 100 \ \Omega^{(2)} \\ V_{CC} &= 10.0 \text{ V}, \text{ I}_{\text{F}} = 5.0 \text{ mA}, \text{ R}_{\text{L}} = 100 \ \Omega^{(2)} \end{split}$

Notes:

1. Measured with input leads shorted together and output leads shorted together.

2. The input waveform is supplied by a generator with the following characteristics: Z_{OUT} = 50 Ω , $t_r \le$ 15 ns, duty cycle ~ 1%, pulse width ~ 100 ms.





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